

R07DS1151EJ0200

Rev.2.00

Sep. 11, 2018

BCR20CM-12LB

600V - 20A - Triac

Medium Power Use

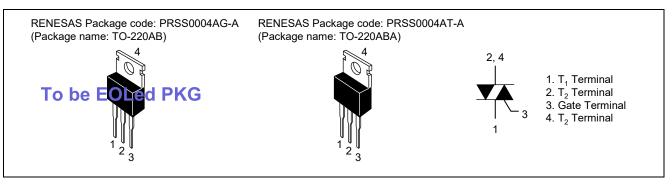
Features

- I_{T (RMS)} : 20 A
- V_{DRM} : 600 V
- I_{FGTI} , I_{RGTI} , $I_{RGT III}$: 30 mA(20mA)^{Note6}

• Tj: 150 °C

- Non-insulated Type
- Planar Passivation Type

Outline



Application

Motor control, Heater control, Power supply, Solid state relay, and other general purpose AC control applications.

Maximum Ratings

Parameter	Symbol	Voltage class	Unit
		12	
Repetitive peak off-state voltage ^{Note1}	V _{DRM}	600	V
Non-repetitive peak off-state voltage ^{Note1}	V _{DSM}	720	V

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	IT (RMS)	20	A	Commercial frequency, sine full wave 360°conduction, Tc = 126°C ^{Note3}
Surge on-state current	I _{TSM}	200	A	60 Hz sinewave 1 full cycle, peak value, non-repetitive
l ² t for fusing	l ² t	167	A²s	Value corresponding to 1 cycle of half wave 60 Hz, surge on-state current
Peak gate power dissipation	Рдм	5	W	
Average gate power dissipation	Pg (AV)	0.5	W	
Peak gate voltage	V _{GM}	10	V	
Peak gate current	lgм	2	А	
Junction Temperature	Tj	-40 to +150	°C	
Storage temperature	Tstg	-40 to +150	°C	



Electrical Characteristics

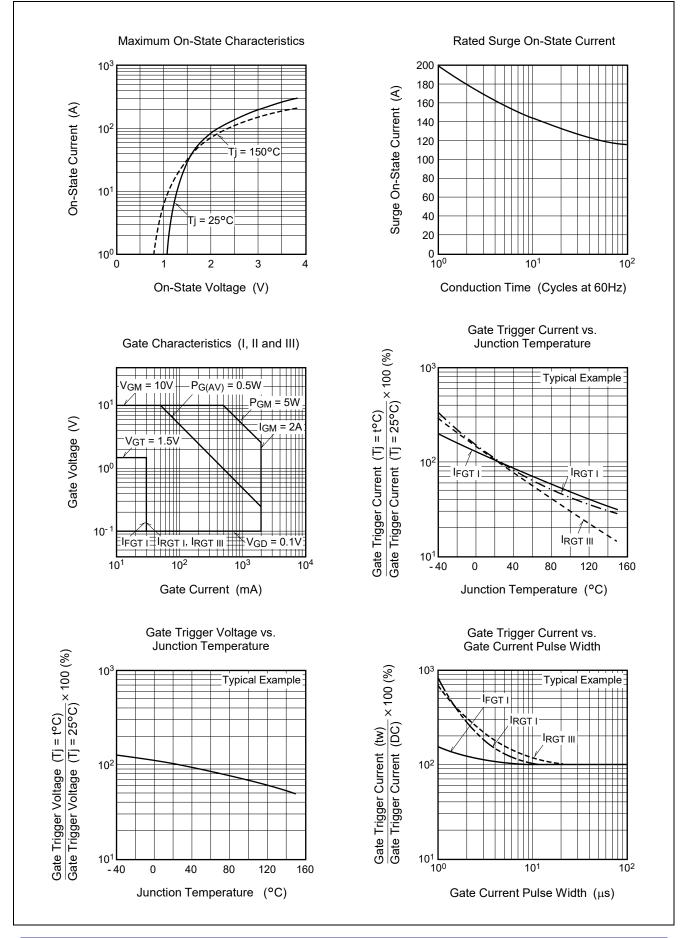
Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak off-state cu	rrent	IDRM	—		2.0	mA	Tj = 125°C, V _{DRM} applied
			—	—	3.0		Tj = 150°C, V _{DRM} applied
On-state voltage		Vtm	_	—	1.5	V	Tc = 25°C, I _{TM} = 30 A,
							instantaneous measurement
Gate trigger voltage ^{Note2}	Ι	V _{FGTI}	—	—	1.5	V	Tj = 25°C, V_D = 6 V, R_L = 6 Ω,
	II	Vrgti	_	_	1.5	V	R _G = 330 Ω
	III	V _{RGTIII}	—	—	1.5	V	
Gate trigger currentNote2	Ι	IFGTI	_	—	30 Note6	mA	Tj = 25°C, V_D = 6 V, R_L = 6 Ω,
	II	IRGTI	—	—	30 Note6	mA	R _G = 330 Ω
	III	Irgtiii	—	—	30 Note6	mA	
Gate non-trigger voltage		V_{GD}	0.2			V	Tj = 125°C, V _D = 1/2 V _{DRM}
			0.1	_	_		Tj = 150°C, V _D = 1/2 V _{DRM}
Thermal resistance		R _{th (j-c)}	_	_	1.2	°C/W	Junction to case ^{Note3 Note4}
Critical-rate of rise of off-state		(dv/dt)c	10			V/μs	Tj = 125°C
commutation voltage ^{Note5}			1	—	—		Tj = 150°C

Notes: 1. Gate open.

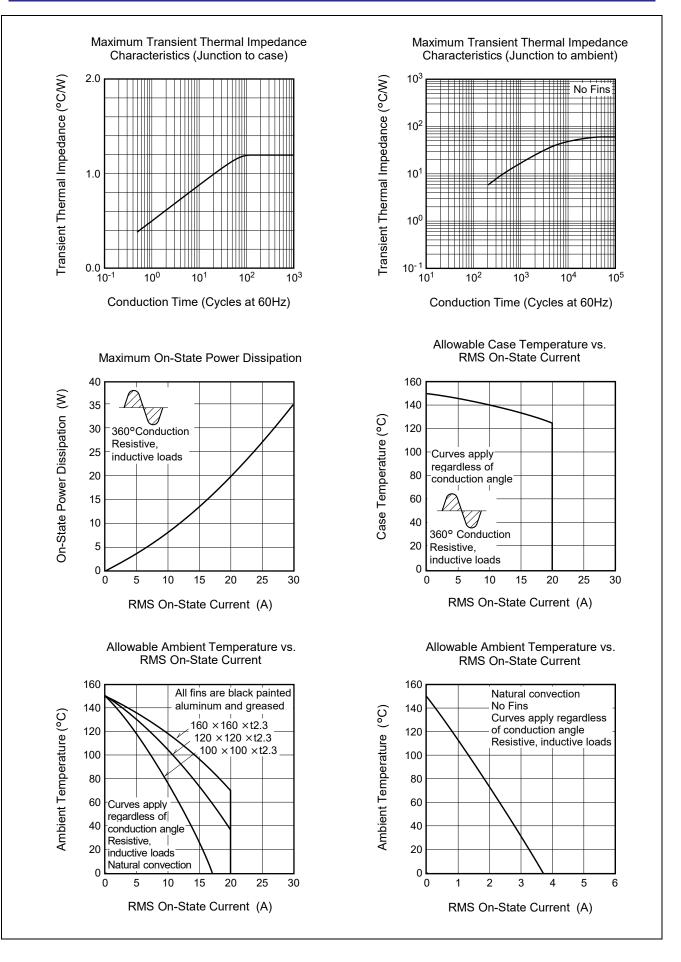
- 2. Measurement using the gate trigger characteristics measurement circuit.
- 3. Case temperature is measured at the T_2 tab 1.5 mm away from the molded case.
- 4. The contact thermal resistance Rth(c-f) in case of greasing is 1.0°C /W.
- 5. Test conditions of the critical-rate of rise of off-state commutation voltage is shown in the table below.
- 6. High sensitivity (I_{GT} \leq 20 mA) is also available. (I_{GT} item:1)

Test conditions	Commutating voltage and current waveforms (inductive load)
 Junction temperature	Supply Voltage → Time
Tj = 125°C/150°C Rate of decay of on-state commutating current	Main Current → Time
(di/dt)c = - 10 A/ms Peak off-state voltage	Main Voltage → Time
V _D = 400 V	(dv/dt)c ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓

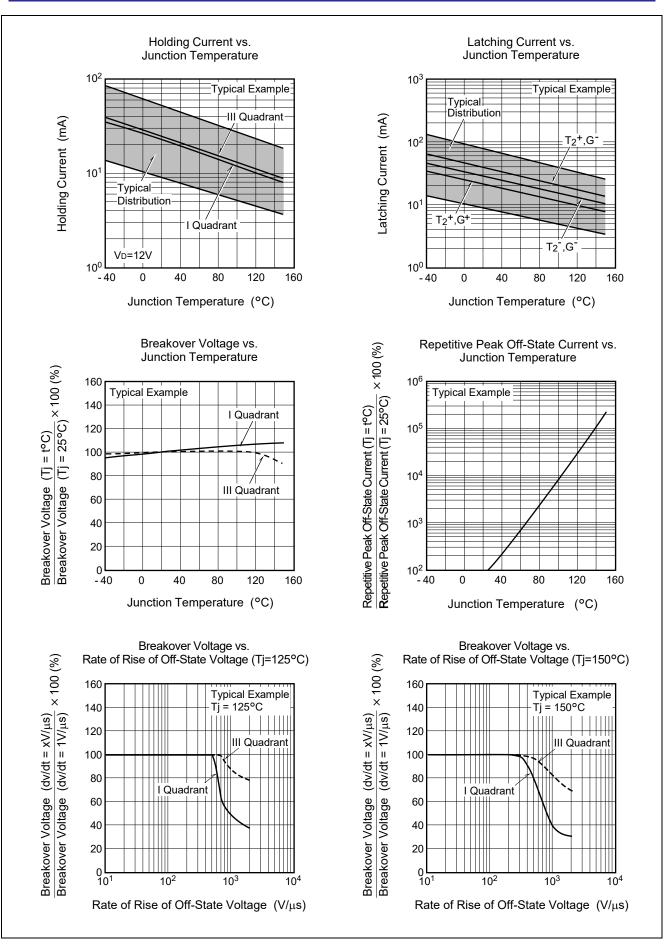
Performance Curves



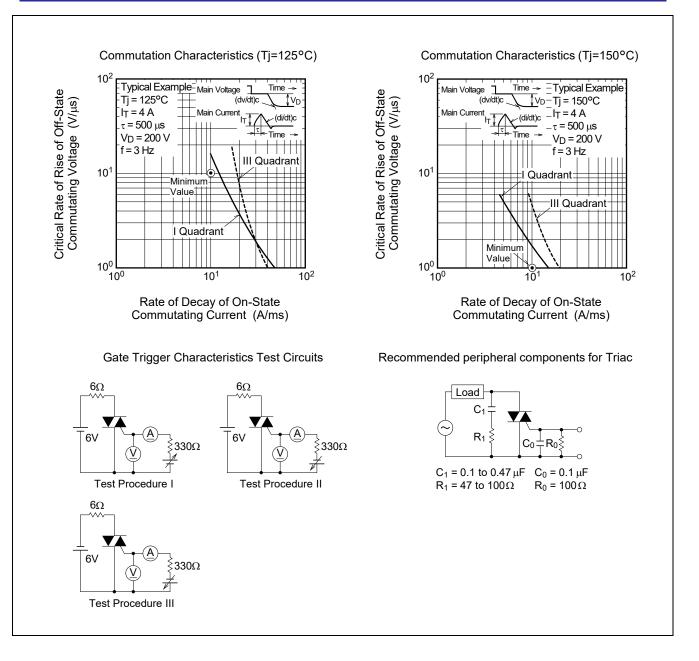




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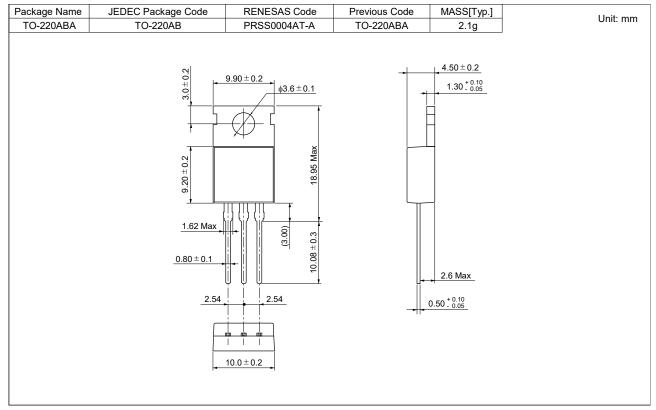




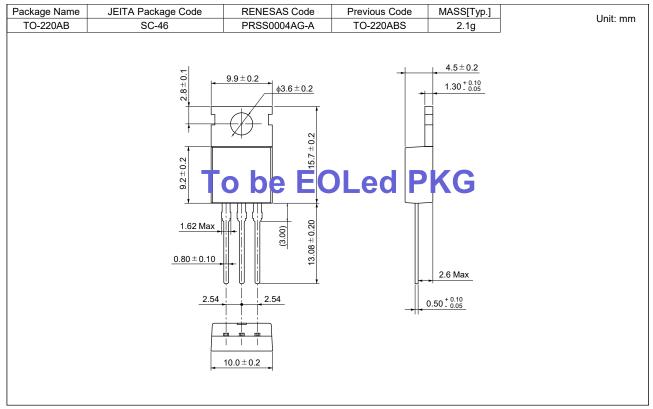


Package Dimensions

Ordering code: #BH0



Ordering code: #BB0





Ordering Information

Orderable Part Number	Package	Quantity Note7	Remark	Status
BCR20CM-12LB#BH0	TO-220ABA	50 pcs./ tube	Straight type	Mass Production
BCR20CM-12LB-1#BH0	TO-220ABA	50 pcs./ tube	Straight type, I _{GT} item:1	
BCR20CM-12LB#BB0	TO-220ABS	50 pcs./ tube	Straight type	EOL Candidate
BCR20CM-12LB-1#BB0	TO-220ABS	50 pcs./ tube	Straight type, I _{GT} item:1	
BCR20CM-12LBDD#BB0	TO-220ABS	50 pcs./ tube	□□:Lead form type	
BCR20CM12LB1DD#BB0	TO-220ABS	50 pcs./ tube	□□:Lead form type, I _{GT} item:1	

Notes: 7. Please confirm the specification about the shipping in detail.

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